

Superfluid density and penetration depth in Fe-pnictides

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(Dated: March 15, 2009)

We consider the superfluid density $\rho_s(T)$ in a two-band superconductor with sign-changing extended s -wave symmetry (s^+) in the presence of non-magnetic impurities and apply the results to Fe-pnictides. We show that the behavior of the superfluid density is essentially the same as in an ordinary s -wave superconductor with magnetic impurities. We show that, for moderate to strong inter-band impurity scattering, $\rho_s(T)$ behaves as a power-law T^n with $n \approx 1.6 \div 2$ over a wide range of T . We argue that the power-law behavior is consistent with recent experiments on the penetration depth $\lambda(T)$ in doped BaFe₂As₂, but disagree quantitatively with the data on LaFePO.

Introduction. Recent discovery of iron-based pnictide superconductors instigated massive theoretical and experimental research effort aimed at unveiling fundamental properties of these materials. Both oxygen containing ‘1111’s materials (La,Nd,Pr,Sm)FeAsO, and oxygen free ‘122’s (Ca,Ba,Sr)Fe₂As₂ have high potential for the applications and may create a breakthrough in the field of superconductivity (SC).¹

One of the central and still unsettled issues is the symmetry of the SC gap. An ordinary s -wave superconductivity due to phonons has been deemed unlikely because of too small electron-phonon coupling,² suggesting that the SC pairing is of electronic origin. Electronic structure of pnictides shows pairs of small hole and electron pockets centered at $(0,0)$ and (π,π) , respectively in the *folded* Brillouin zone.^{2,3,4} Most of parent compounds display an SDW order with momentum at, or near (π,π) , and an early scenario was the pairing mediated by antiferromagnetic spin fluctuations.⁵ For pnictide geometry, this mechanism yields an extended s -wave gap which changes sign between hole and electron pockets but remains approximately uniform along either of them (an s^+ gap). The s^+ gap symmetry has been found in weak coupling studies of two-band⁶ and five-band⁷ “ g -ology” models of interacting low-energy fermions. Some other studies, however, found a gap with extended s -wave symmetry in the *unfolded* Brillouin zone.⁸ Such gap has no nodes on the hole Fermi surface (FS), but has four nodes on the electron FS, like a d -wave gap in the cuprates. The uncertainty arises from the fact that in pnictides there is a competition between the inter-pocket interaction with large momentum transfer and intra-pocket repulsion. When inter-pocket interaction is stronger, the system likely develops a sign-changing s -wave gap without nodes; when intra-pocket repulsion is stronger, the system develops an extended s -wave gap with nodes to minimize the effect of intra-pocket repulsion.⁹

From experimental perspective, the situation is also unclear. Andreev spectroscopy¹⁰ and ARPES measurements¹¹ are consistent with the gap without nodes. NMR and Knight shift measurements¹² were originally interpreted as evidence of a gap with nodes, but it turns out that the data can be fitted equally well by a dirty s^+ superconductor.^{6,13} The situation is further complicated by the fact that the two hole FS are of dif-

ferent sizes, and have different gaps.¹⁴

To truly distinguish between s^+ gap and a gap with the nodes one should go to very low temperatures. Recently, two groups reported measurements of the penetration depth $\lambda(T)$ down to $10^{-2} T_c$. The data seem to point into different directions. Ames group reported the data on Co- and K-doped BaFe₂As₂ (Ref. 15) and demonstrated that down to the lowest T and for all dopings the T dependence of $\lambda(T) = \lambda(0) + \Delta\lambda(T)$ can be fitted by $\Delta\lambda(T) \propto T^2$. In SmFeAsO_{1-x}F_x¹⁶ and PrFeAsO¹⁷ penetration depth seems to have an exponential temperature dependence at low T , consistent with the gap without nodes. At the same time, in another 1111 material, LaFePO, the Bristol group has found $\Delta\lambda \propto T^{1.2}$ down to the lowest temperatures.¹⁸ FS in this material has been reconstructed from magneto-oscillation measurements¹⁹ and consists of weakly corrugated small-size cylinders making it unlikely that either hole or electron FSs extend to the points where s^+ order parameter changes sign.

The penetration depth in the clean limit was considered in Ref. 20 for an s^+ gap and in Ref. 21 for several other gap symmetries. For a gap without nodes, $\Delta\lambda(T)$ is obviously exponential at low T , for a gap with nodes it is linear in T . In this paper we discuss to what extent the existing data for $\lambda(T)$ can be described by a dirty SC with an s^+ gap symmetry, and non-magnetic impurities. We argue that the T^2 behavior observed by Ames group in 122 materials can be fitted over a wide temperature range for various dopings and in this respect the results for the penetration depth are not in conflict with ARPES and other measurements which show SC gap without nodes. The existence of the two different gaps on the two hole FS makes the agreement between experiments even better. On the other hand, the linear in T behavior observed in LaFePO is not reproduced, and it is more likely that the gap in this material has nodes, as suggested in Ref. 8.

For a conventional s -wave SC the effect of non-magnetic impurities on the temperature dependence of $\lambda(T)$ is small and mostly irrelevant for all T . For s^+ superconductors, the situation is qualitatively different because inter-band impurity scattering Γ_π mixes hole and electron states with opposite values of the order parameter $\pm\Delta$ and in this respect should be pairbreaking and act in the same way as a magnetic impurity in a conven-

tional s -wave superconductor. Consequently, scattering by non-magnetic impurities in s^+ SC affects T_c , the density of states, and the temperature dependence of the penetration depth. Over some range of Γ_π/Δ , the behavior at the lowest T is still exponential, however when Γ_π/Δ becomes larger than a critical value, superconductivity becomes gapless, and the exponential behavior disappears.

Method. The London penetration depth $\lambda(T)$ scales as $1/\sqrt{\rho_s(T)}$, where $\rho_s(T)$ is the superfluid density. The latter is, up to a factor, the zero frequency value of the current-current correlation function and can be written in the form²²

$$\frac{\rho_s(T)}{\rho_{s0}} = \pi T \sum_m \frac{\tilde{\Delta}_m^2}{(\tilde{\Delta}_m^2 + \tilde{\omega}_m^2)^{3/2}}, \quad (1)$$

where ρ_{s0} is the superfluid density at $T = 0$ in the absence of impurities. The integrand in Eq. (1) is defined in terms of impurity-renormalized Matsubara energy, $\tilde{\omega}_m$, and the superconducting vertex $\tilde{\Delta}_m$. In an s^+ superconductor the order parameters on the hole (c) and electron (f) FS pockets are related, $\tilde{\Delta}_m^c = -\tilde{\Delta}_m^f = \tilde{\Delta}_m$ and in Born approximation

$$i\tilde{\omega}_m = i\omega_m - \Gamma_0 g^c(\tilde{\omega}_m, \tilde{\Delta}_m) - \Gamma_\pi g^f(\tilde{\omega}_m, \tilde{\Delta}_m), \quad (2a)$$

$$\tilde{\Delta}_m = \Delta + \Gamma_0 f^c(\tilde{\omega}_m, \tilde{\Delta}_m) + \Gamma_\pi f^f(\tilde{\omega}_m, \tilde{\Delta}_m), \quad (2b)$$

where $\omega_m = \pi T(2m + 1)$, $\Gamma_0 = \pi n_i N_F |u_0|^2$ and $\Gamma_\pi = \pi n_i N_F |u_\pi|^2$ are the intra- and inter-band impurity scattering rates, respectively ($u_{0,\pi}$ are impurity scattering amplitudes with correspondingly small, or close to $\pi = (\pi, \pi)$, momentum transfer), Δ is the SC order parameter, and functions $g^{c,f}$ and $f^{c,f}$ are ξ -integrated normal and anomalous Green's functions for holes and electrons:

$$g^c = g^f = \frac{-i\tilde{\omega}_m}{\sqrt{\tilde{\omega}_m^2 + \tilde{\Delta}_m^2}}, \quad f^c = -f^f = \frac{\tilde{\Delta}_m}{\sqrt{\tilde{\omega}_m^2 + \tilde{\Delta}_m^2}} \quad (3)$$

Since the f -function has opposite signs in two bands, Γ_π has the same effect on anomalous self-energy as the scattering on magnetic impurities in an ordinary s -wave superconductor. Following the customary path one may introduce $\eta_m = \tilde{\omega}_m/\omega_m$ and $\bar{\Delta}_m = \tilde{\Delta}_m/\eta_m$ that satisfy

$$\eta_m = 1 + (\Gamma_0 + \Gamma_\pi) \frac{1}{\sqrt{\Delta_m^2 + \omega_m^2}}; \quad (4a)$$

$$\bar{\Delta}_m = \Delta(T) - 2\Gamma_\pi \frac{\bar{\Delta}_m}{\sqrt{\bar{\Delta}_m^2 + \omega_m^2}}. \quad (4b)$$

The order parameter $\Delta(T)$ is determined by the self-consistency equation

$$\Delta(T) = V^{sc} \pi T \sum_{\omega_m}^{\Lambda} f^c(\tilde{\omega}_m, \tilde{\Delta}_m) = \pi T \sum_{\omega_m}^{\Lambda} \frac{V^{sc} \bar{\Delta}_m}{\sqrt{\bar{\Delta}_m^2 + \omega_m^2}}, \quad (5)$$

where V^{sc} is the s^+ coupling constant and Λ is the ultraviolet cutoff. Notice that the last expression contains $\bar{\Delta}_m$ and bare Matsubara frequencies ω_m . Eqs. (2)-(5) can be extended to the case when the gaps on hole and electron FS have different magnitudes.

Solutions of the system of Eqs. (4b) and (5) give the values of $\Delta(T)$ and $\bar{\Delta}_m$. In particular, Eq. (4b) is an algebraic equation (valid at any T) which expresses $\bar{\Delta}_m$ in terms of Δ . The latter itself depends on Γ_π , because the self-consistency equation (5) contains $\bar{\Delta}_m$. Without inter-band scattering ($\Gamma_\pi = 0$) we have $\bar{\Delta}_m = \Delta = \Delta_0 = 1.76 T_{c0}$, where T_{c0} and Δ_0 are the BCS transition temperature and the $T = 0$ gap in a clean superconductor. For $\Gamma_\pi \neq 0$, $\bar{\Delta}_m$ differs from Δ , and Δ differs from Δ_0 . Converted to real frequencies, Eqs. (4b) and (5) yield a complex function $\bar{\Delta}(\omega)$. For $2\Gamma_\pi \geq \Delta$, $\bar{\Delta}(\omega = 0)$ vanishes, i.e., superconductivity becomes gapless.²³ At the critical point $2\Gamma_\pi = \Delta$, $\bar{\Delta}(\omega) \propto (-i\omega)^{2/3}$ at small ω , at larger Γ_π , $\bar{\Delta}(\omega) = -i \text{const } \omega + O(\omega^2)$.

Results. We express the results using dimensionless parameter $\zeta = \Gamma_\pi/2\pi T_{c0}$. For equal gap magnitudes and $2\Gamma_\pi/\Delta < 1$, $y = \Delta/\Delta_0$ is the solution of $y = \exp[-\pi e^\gamma \zeta/y]$, where $\gamma \approx 0.577$ is the Euler constant.²⁴ At a given T a gapless superconductivity emerges, when y becomes smaller than $4\zeta e^\gamma$, i.e., for $\zeta > (1/4) \exp[-(\gamma + \pi/4)] \approx 0.064$. The transition temperature obeys^{23,24} $\ln(T_c/T_{c0}) = \Psi(1/2) - \Psi(1/2 + 2\zeta T_{c0}/T_c)$, where $\Psi(x)$ is the di-Gamma function, Fig. 1a. T_c decreases with ζ and vanishes at $\zeta_{cr} = e^{-\gamma}/8 \approx 0.07$ ($\Gamma_\pi/\Delta_0 = 1/4$). For $0.064 < \zeta < \zeta_{cr}$, $\bar{\Delta}(T, \omega) \propto i\omega$ for small ω , including $T = 0$, and thus even $T = 0$ zero-energy density of states becomes finite. (At the onset, at $\zeta = 0.064$, $T_c \approx 0.22 T_{c0}$, and $\Delta(0) = 0.46 \Delta_0$). The ratio $2\Delta(0)/T_c$ increases with ζ and reaches 7.2 at the onset of the gapless behavior and 8.88 at $\zeta = \zeta_{cr}$ (Ref. 24). A large value of $2\Delta(0)/T_c$ is often attributed to strong coupling,²⁵ but, as we see, can also be due to impurities.

In terms of auxiliary $\bar{\Delta}_m$ and η_m ,

$$\frac{\rho_s(T)}{\rho_{s0}} = \pi T \sum_{\omega_m} \frac{\bar{\Delta}_m^2}{\eta_m (\bar{\Delta}_m^2 + \omega_m^2)^{3/2}}. \quad (6)$$

In general, the value of $\rho_s(T = 0)$ and the functional form of $\rho_s(T)$ depend on both Γ_π and Γ_0 because Γ_0 is explicitly present in Eq. (6) via η_m given by Eq. (4a). Impurity scattering amplitude is a decreasing function of momentum transfer, and, in general, $\Gamma_0 \gg \Gamma_\pi$. Since we are interested in $\Gamma_\pi \sim \Delta$, we have $\Gamma_0 \gg \Delta$ and

$$\rho_s(T) \approx BT \sum_{\omega_m} \frac{\bar{\Delta}_m^2}{\bar{\Delta}_m^2 + \omega_m^2}, \quad (7)$$

where $B = \pi \rho_{s0}/(\Gamma_0 + \Gamma_\pi)$. We see that Γ_0 only affects the overall factor B , and all non-trivial T dependence comes from frequency and temperature dependence of $\bar{\Delta}_m$.

Several results for $\rho_s(T)$ given by (7) can be obtained analytically. First, near T_c , $\rho_s(T) \propto \Delta^2(T) \propto T_c - T$,

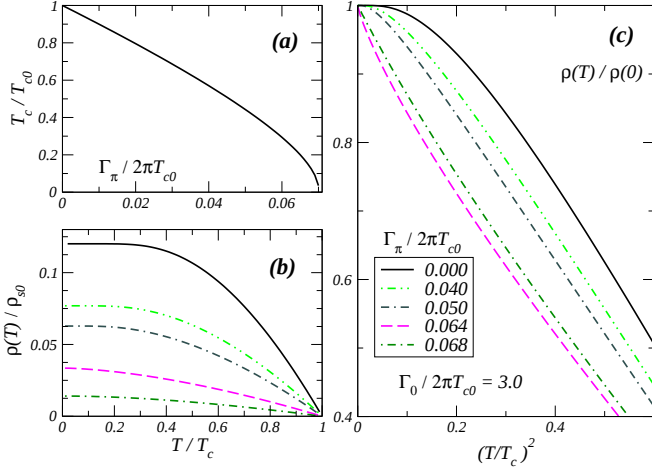


FIG. 1: (color online) (a) Suppression of T_c by inter-band scattering in a two-band ($\Delta, -\Delta$) model; (b) superfluid stiffness $\rho_s(T)$ in a dirty s^+ superconductor for fixed intra-band impurity scattering $\Gamma_0/2\pi T_{c0} = 3$, and various inter-band scatterings $\zeta = \Gamma_\pi/2\pi T_{c0}$; and (c) low- T plot of ρ_s vs. T^2 showing near $n = 2$ power-law around onset of gapless regime.

i.e.,

$$\frac{\rho_s}{\rho_s(T=0)} = B(\zeta) \left(1 - \frac{T}{T_c}\right), \quad (8)$$

where $\rho_s(T=0)$ is the actual zero-temperature value of ρ_s . In a clean BCS superconductor $B = 2$. In the present dirty case ($\Gamma_0 \gg T_c, \Gamma_\pi$) $B(\zeta)$ is non-monotonic in ζ and equals $B(\zeta \rightarrow 0) \approx 2.65$, $B(\zeta = 0.064) \approx 1.67$, $B(\zeta \approx \zeta_{cr}) = 2.03$. This implies that a linear extrapolation of ρ_s from $T \approx T_c$ to $T = 0$ still yields a significantly larger value than the actual $\rho_s(0)$. Second, at $\zeta < 0.064$, the T dependence of $\rho_s(T)$ remains exponential at low T , $\rho_s(T) \propto e^{-\bar{\Delta}(\omega=0)/T}$ with $\bar{\Delta}(\omega=0) = \Delta_0[1 - (\zeta/\zeta_{cr})^{2/3}]^{3/2}$, but at the onset of gapless superconductivity, when $\bar{\Delta}(\omega) \propto (-i\omega)^{2/3}$, we have $\rho_s(T) \propto T^{5/3}$. Finally, in the gapless regime $0.064 < \zeta < \zeta_{cr}$, we found $\rho_s(T) \propto T^2$ at low T .

To obtain $\rho_s(T)$ at arbitrary T , we self-consistently solved the gap equation (5) together with impurities (2) and Green's functions (3) numerically, found $\Delta(T)$ and $\tilde{\Delta}_m$, substituted them into Eq. (1) and obtained $\rho_s(T)$. We present the results in Fig. 1 for several values of ζ .

We see that, once the inter-band impurity scattering increases, the range of exponential behavior of $\rho_s(T)$ progressively shrinks to smaller T , Fig. 1b. Outside this low T -range, the temperature dependence of ρ_s strongly resembles T^2 behavior, see Fig. 1(c). The $T^{5/3}$ behavior at the onset of gapless superconductivity is hard to see numerically, as this power is confined to very low T , while for slightly larger T the behavior is again close to T^2 . Overall, the behavior of the superfluid density in a relatively wide range of ζ is a power-law T^n with n reasonably close to 2 down to quite low T . At the same time, we didn't find conditions under which the superfluid density

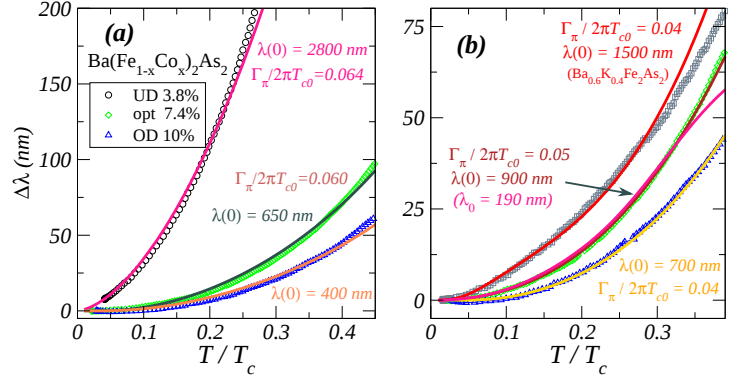


FIG. 2: (color online) The fits to experimental data for BaFe_2As_2 (Ref.15). We use only low- T data as at higher T the experimental $\lambda(T)$ may be influenced by sample geometry and fluctuations. (a) The data for electron-doped BaFe_2As_2 for optimally doped ($x = 7.4\%$) and overdoped ($x = 10\%$) samples can be fitted reasonably well using ($\Delta, -\Delta$)-model; (b) The fit of data for two Co-doped ($x = 7.3\%, 10\%$) and one K-doped samples with a phenomenological extension of the presented two-band model to the case of four gaps. We set gaps to be $(\Delta, -\Delta; \Delta, -\Delta_h)$ with $\Delta_h = \Delta/3, \Delta/2$. In this case the pairbreaking parameter does not need to be large. The fitting values of $T = 0$ penetration length are large but for $x = 7.4\%$ sample we show a fit with inclusion of Fermi-liquid effects that reduces this parameter to $\lambda_{\text{FL}}(0) \equiv \lambda_0 \sim 190$ nm, in agreement with experimental values.

would be linear at low T .

Comparison with the data. Judging by the value of $2\Delta(0)/T_c$,¹⁶ the material with the least amount of inter-band impurity scattering is $\text{SmFeAsO}_{1-x}\text{F}_x$, where $T_c \sim 55\text{K}$. In this compound it is difficult to expect a large ζ , since the observed exponential BCS-like behavior of $\rho_s(T)$ at small T (Ref. 16) is consistent with extended s -wave gap and weak inter-band impurity scattering.²⁰

The data for electron- and hole-doped BaFe_2As_2 (Ref. 15) is fitted in Fig. 2a,b. The measured $\rho_s(T)$ scales approximately as T^2 , which is similar to behavior shown in Fig. 1(c). Left panel is the fit assuming that the gaps on two electron FSs and two hole FSs are $\Delta, -\Delta$; right panel is a more realistic fit in which we assumed, guided by ARPES data,¹⁴ that the gaps on the inner hole and the two electron FS are the same, but the gap on the other FS is 2-3 times smaller.

The values $\zeta = 0.04 - 0.06$ used in these fits correspond to $T_c/T_{c0} \sim 0.6 - 0.3$ which is consistent with the values of $T_c \sim 10 - 30\text{K}$ in this material, if we assume that T_{c0} in the clean case is roughly the same as in SmFeAsO . The curves shown in Figs. 2a,b represent the best fits, but we emphasize that we do not need to adjust ζ to get a T^2 behavior – it persists over a range of ζ , see Fig.1c. However we note that $\lambda(0)$ used in the fits is rather large compared with the experimentally obtained values $\sim 200 - 300$ nm.¹⁵ We suggest that this discrepancy may be due to the omission of Fermi-liquid effects. The qualitative argument, supported by numeri-

cal estimates, is as follows. Assume, by analogy with the cuprates, that fermion-fermion interactions renormalize $\omega \rightarrow \omega Z_\omega$, where Z_ω is a decaying function of frequency, and further assume that $Z_\omega \approx 1$ at energies comparable to Δ so that it does not affect the relation between $\Delta(0)$ and T_c . Then we find that the low-temperature dependence $f(T/T_c)$ of the penetration length is rescaled $\Delta\lambda/\lambda_0 \sim f(Z_0 T/T_c)$ and the value of the fitting parameter $\lambda_0 \equiv \lambda_{FL}(0)$ decreases compared to what is obtained without Fermi liquid effects. This Z factor is particularly relevant to heavily underdoped regime where it increases because of SDW fluctuations. We believe this is the reason why we have to use very large $\lambda(0) = 2800\text{nm}$ to fit the data. At larger dopings, Z is smaller, but according to ARPES,¹¹ $Z \sim 2$ in optimally doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$. For $f \sim T^2$, from the analytic reasoning we get the effective λ_0 four times smaller than $\lambda(0)$, reducing it to $\lambda_0 \sim 150\text{--}400\text{ nm}$, in the range of what is experimentally extracted. The numerical analysis confirms this and for $Z = 2$ we show a fit for one of the electron-doped samples, that gives a reasonable value for the zero-temperature penetration length. We therefore conclude that the penetration depth data for 122 material can be fitted by a model of a dirty s^+ superconductor. Note in this regard that the data²⁶ show that T_c is almost insensitive to the value of residual resistivity. This was interpreted as the argument for a conventional s -wave gap. We note that this is also the case for extended s -wave gap as the dominant impurity scattering is intra-band scattering, controlled by Γ_0 , which affects residual resistivity but does not affect T_c .

We attempted to fit the data for LaFePO using this approach but the fit fails for all ζ and one has to assume unrealistically large $\lambda(0)$ to get even mediocre agreement

with the data. From this perspective, it is likely that the linear in T behavior of $\lambda(T)$ in LaFePO is not related to impurities but rather is the consequence of the fact that the gap in this material has nodes.

Conclusions. In this paper we considered superfluid density $\rho_s(T)$ in a multi-band superconductor with sign-changing s^+ -symmetry in the presence of non-magnetic impurities and applied the results to Fe-pnictides. We showed that the behavior of the superfluid density is essentially the same as in an ordinary s -wave superconductor with magnetic impurities. For a moderate *inter-band* impurity scattering, $\rho_s(T)$ over a wide range of T behaves roughly as T^2 and crosses over to exponential behavior only at very low T . When superconductivity becomes gapless at $T = 0$, the T^2 behavior extends to the lowest T . We argue that this power-law behavior is consistent with recent experiments on penetration depth $\lambda(T)$ in hole and electron doped BaFe_2As_2 , but we find that the present model does not explain the data for LaFePO .

Several modifications of the model may improve the comparison with the experimental data. First, an extension beyond Born approximation may further flatten the T dependence of $\lambda(T)$, although recent study for a different model²⁸ didn't find much changes beyond Born approximation. Second, we assumed that the surface of a superconductor sample is homogeneous. Defects on the surface may also modify the temperature dependence of the penetration depth.

We acknowledge with thanks useful discussions with A. Carrington, I. Eremin, R. Prozorov and J. Schmalian. We thank R. Prozorov and A. Carrington for sharing with us the data of Refs. 15,18 prior to publication. This work was supported by nsf-dmr 0604406 (A.V.Ch).

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